NE3509M04-T2"供应简HETERO JUNCTION FIELD EFFECT TRANSISTOR NE3509M04

L TO S BAND LOW NOISE AMPLIFIER N-CHANNEL HJ-FET

FEATURES

- · Super low noise figure and high associated gain
 - NF = 0.4 dB TYP., Ga = 17.5 dB TYP. @ f = 2 GHz, Vos = 2 V, Io = 10 mA
- Flat-lead 4-pin thin-type super minimold (M04) package

APPLICATIONS

- Satellite radio (SDARS, DMB, etc.) antenna LNA
- GPS antenna LNA
- · Low noise amplifier for microwave communication system

ORDERING INFORMATION

Part Number	Order Number	Package	Quantity	Marking	Supplying Form
NE3509M04	NE3509M04-A	Flat-lead 4-pin thin-	50 pcs (Non reel)	V80	8 mm wide embossed taping
NE3509M04-T2	NE3509M04-T2-A	type super minimold (M04) (Pb-Free)	3 kpcs/reel		• Pin 1 (Source), Pin 2 (Drain) face the perforation side of the tape

Remark To order evaluation samples, contact your nearby sales office. Part number for sample order: NE3509M04

ABSOLUTE MAXIMUM RATINGS (TA = +25°C)

Parameter	Symbol	Ratings	Unit
Drain to Source Voltage	Vds	4.0	V
Gate to Source Voltage	Vgs	-3.0	V
Drain Current	lь	loss	mA
Gate Current	lg	200	μA
Total Power Dissipation	Ptot Note	150	mW
Channel Temperature	Tch	+150	°C
Storage Temperature	Tstg	-65 to +150	°C

Note Mounted on 1.08 $\text{cm}^2 \times 1.0 \text{ mm}$ (t) glass epoxy PCB

Caution Observe precautions when handling because these devices are sensitive to electrostatic discharge.

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.

_____ 查询"NE3509M04-T2"供应商

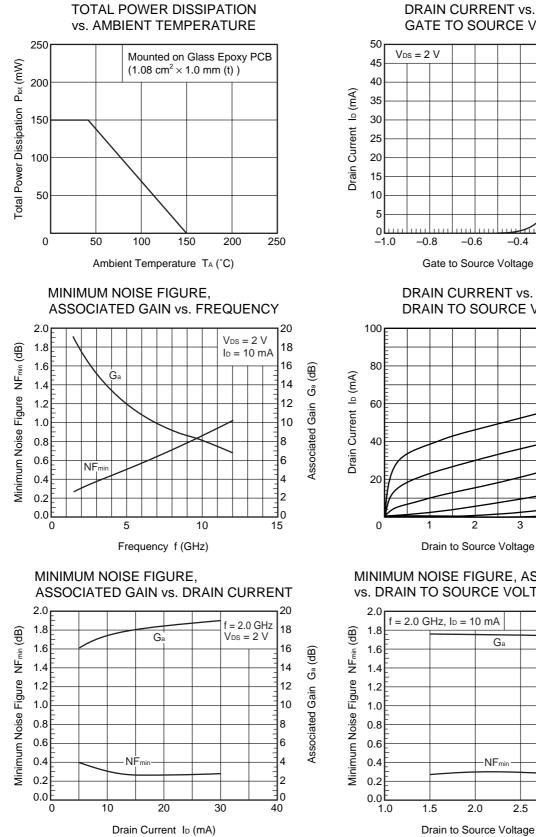
RECOMMENDED OPERATING CONDITIONS (TA = +25°C)

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Drain to Source Voltage	Vds	-	2	3	V
Drain Current	lo	-	10	20	mA
Input Power	Pin	-	-	0	dBm

ELECTRICAL CHARACTERISTICS (T_A = +25°C, unless otherwise specified)

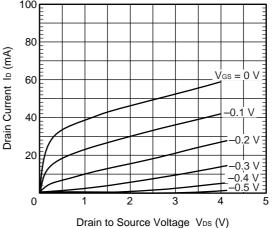
Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Gate to Source Leak Current	lgso	Vgs = -3 V	-	0.5	10	μA
Saturated Drain Current	loss	$V_{DS} = 2 V, V_{GS} = 0 V$	30	45	60	mA
Gate to Source Cutoff Voltage	VGS (off)	$V_{DS} = 2 V$, $I_D = 50 \mu A$	-0.25	-0.5	-0.75	V
Transconductance	gт	Vps = 2 V, Ip = 10 mA	80	-	-	mS
Noise Figure	NF	V _{DS} = 2 V, I _D = 10 mA, f = 2 GHz	-	0.4	0.7	dB
Associated Gain	Ga		16	17.5	-	dB
Gain 1 dB Compression	P O (1 dB)	Vps = 2 V, Ip = 10 mA (Non-RF),	-	11	-	dBm
Output Power		f = 2 GHz				

TYPICAL CHARACTERISTICS (TA = +25°C, unless otherwise specified)

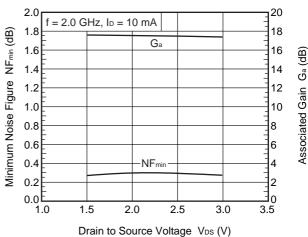


GATE TO SOURCE VOLTAGE $V_{DS} = 2 V$ -0.8 -0.6 -0.4-0.20 Gate to Source Voltage Vgs (V)

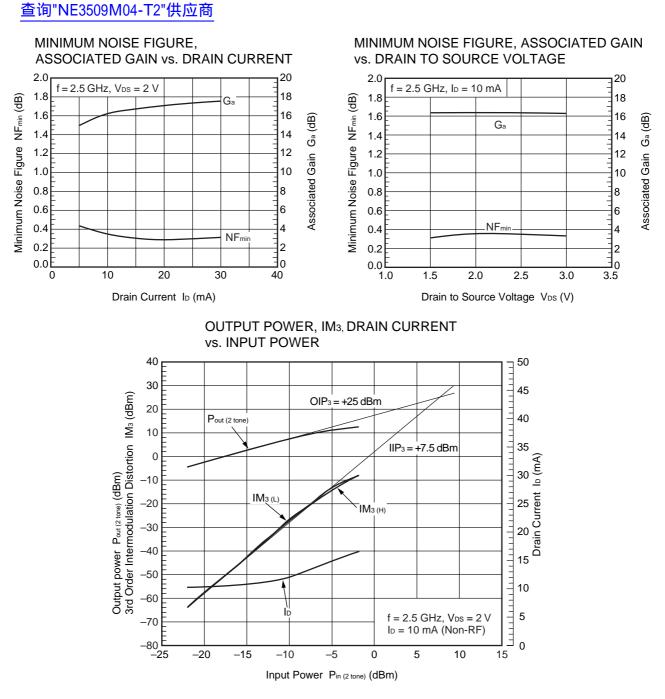
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



MINIMUM NOISE FIGURE, ASSOCIATED GAIN vs. DRAIN TO SOURCE VOLTAGE



Remark The graphs indicate nominal characteristics.



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S-PARAMETERS

S-parameters/Noise parameters are provided on our web site in a form (S2P) that enables direct import to a microwave circuit simulator without keyboard input.

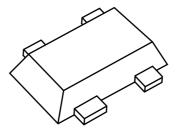
Click here to download S-parameters.

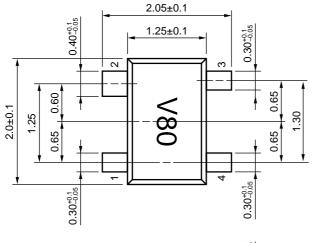
[RF and Microwave] \rightarrow [Device Parameters]

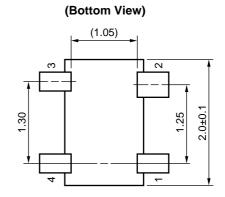
URL http://www.ncsd.necel.com/

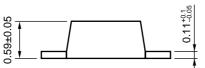
PACKAGE DIMENSIONS

FLAT-LEAD 4-PIN THIN-TYPE SUPER MINIMOLD (M04) (UNIT: mm)







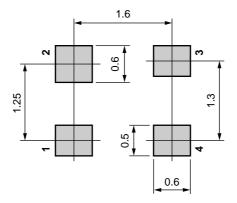


PIN CONNECTIONS

- 1. Source
- 2. Drain
- 3. Source
- 4. Gate

MOUNTING PAD DIMENSIONS (REFERENCE ONLY)

FLAT-LEAD 4-PIN THIN-TYPE SUPER MINIMOLD (M04) PACKAGE (UNIT: mm)



RECOMMENDED SOLDERING CONDITIONS

This product should be soldered and mounted under the following recommended conditions. For soldering methods and conditions other than those recommended below, contact your nearby sales office.

Soldering Method	Soldering Conditions		Condition Symbol
Infrared Reflow	Peak temperature (package surface temperature) Time at peak temperature Time at temperature of 220°C or higher Preheating time at 120 to 180°C Maximum number of reflow processes Maximum chlorine content of rosin flux (% mass)	: 260°C or below : 10 seconds or less : 60 seconds or less : 120±30 seconds : 3 times : 0.2%(Wt.) or below	IR260
Partial Heating	Peak temperature (terminal temperature) Soldering time (per side of device) Maximum chlorine content of rosin flux (% mass)	: 350°C or below : 3 seconds or less : 0.2%(Wt.) or below	H\$350

Caution Do not use different soldering methods together (except for partial heating).



4590 Patrick Henry Drive Santa Clara, CA 95054-1817 Telephone: (408) 919-2500 Facsimile: (408) 988-0279

Subject: Compliance with EU Directives

CEL certifies, to its knowledge, that semiconductor and laser products detailed below are compliant with the requirements of European Union (EU) Directive 2002/95/EC Restriction on Use of Hazardous Substances in electrical and electronic equipment (RoHS) and the requirements of EU Directive 2003/11/EC Restriction on Penta and Octa BDE.

CEL Pb-free products have the same base part number with a suffix added. The suffix –A indicates that the device is Pb-free. The –AZ suffix is used to designate devices containing Pb which are exempted from the requirement of RoHS directive (*). In all cases the devices have Pb-free terminals. All devices with these suffixes meet the requirements of the RoHS directive.

This status is based on CEL's understanding of the EU Directives and knowledge of the materials that go into its products as of the date of disclosure of this information.

Restricted Substance per RoHS	Concentration Limit per RoHS (values are not yet fixed)	Concentration contained in CEL devices	
Lead (Pb)	< 1000 PPM	-A Not Detected	-AZ (*)
Mercury	< 1000 PPM	Not Detected	
Cadmium	< 100 PPM	Not Detected	
Hexavalent Chromium	< 1000 PPM	Not Detected	
РВВ	< 1000 PPM	Not Detected	
PBDE	< 1000 PPM	Not Detected	

If you should have any additional questions regarding our devices and compliance to environmental standards, please do not hesitate to contact your local representative.

In no event shall CEL's liability arising out of such information exceed the total purchase price of the CEL part(s) at issue sold by CEL to customer on an annual basis.

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